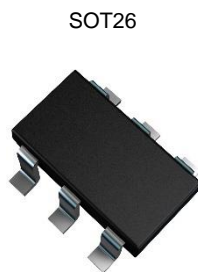


Features

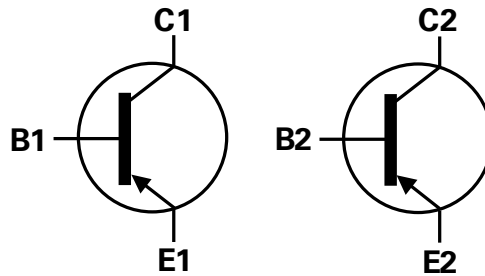
- $BV_{CEO} > -150V$
- $I_C = -200mA$ High Collector Current
- Pair of PNP Transistors That Are Intrinsically Matched (Note 1)
- 2% Matched Tolerance, h_{FE} , $V_{CE(sat)}$, $V_{BE(sat)}$
- Ideal for Medium Power Amplification and Switching
- Fully Internally Isolated in a Small Surface-Mount Package
- Epitaxial Planar Die Construction
- **Totally Lead-Free & Fully RoHS Compliant (Notes 2 & 3)**
- **Halogen and Antimony Free. "Green" Device (Note 4)**
- **For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at <https://www.diodes.com/products/automotive/automotive-products/>.**
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability. <https://www.diodes.com/quality/product-definitions/>

Mechanical Data

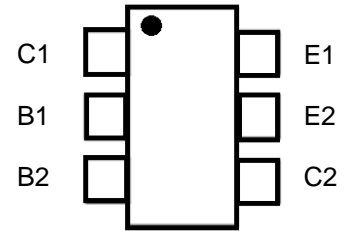
- Package: SOT26
- Package Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.018 grams (Approximate)



Top View



Device Symbol



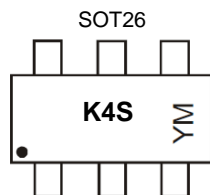
Top View
Pin-Out

Ordering Information (Note 5)

Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
DMMT5401-7-F	SOT26	K4S	7	8	3000	Reel

- Notes:
1. Intrinsically matched pair as this is built with adjacent die from the same wafer.
 2. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 3. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 4. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 5. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



K4S = Product Type Marking Code
YM = Date Code Marking
Y = Year (ex: L = 2024)
M = Month (ex: 3 = March)

Date Code Key

Year	2005	-	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	S	-	L	M	N	P	R	S	T	U	V	W

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-160	V
Collector-Emitter Voltage	V _{CEO}	-150	V
Emitter-Base Voltage	V _{EBO}	-5	V
Collector Current	I _C	-200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation Total Device (Notes 6 & 7)	P _D	300	mW
Thermal Resistance, Junction to Ambient (Note 6)	R _{θJA}	417	°C/W
Thermal Resistance, Junction to Case (Note 6)	R _{θJC}	156	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Collector-Base Breakdown Voltage	BV _{CBO}	-160	—	—	V	I _C = -100μA, I _E = 0
Collector-Emitter Breakdown Voltage	BV _{CEO}	-150	—	—	V	I _C = -1mA, I _B = 0
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	—	—	V	I _E = -10μA, I _C = 0
Collector-Base Cutoff Current	I _{CBO}	—	—	-50	nA μA	V _{CB} = -120V, I _E = 0 V _{CB} = -120V, I _E = 0, T _A = +100°C
Emitter-Base Cutoff Current	I _{EBO}	—	—	-50	nA	V _{EB} = -3V, I _B = 0
ON CHARACTERISTICS (Note 8)						
DC Current Gain (Note 9)	h _{FE}	50 60 50	—	240	—	I _C = -1mA, V _{CE} = -5V I _C = -10mA, V _{CE} = -5V I _C = -50mA, V _{CE} = -5V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	—	—	-0.2 -0.5	V	I _C = -10mA, I _B = -1mA I _C = -50mA, I _B = -5mA
Base-Emitter Saturation Voltage	V _{BE(sat)}	—	—	-1	V	I _C = -10mA, I _B = -1mA I _C = -50mA, I _B = -5mA
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	f _T	100	—	300	MHz	V _{CE} = -10V, I _C = -10mA, f = 100MHz
Output Capacitance	C _{OBO}	—	—	6	pF	V _{CB} = -10V, f = 1.0MHz, I _E = 0
Small Signal Current Gain	h _{fe}	40	—	260	—	V _{CE} = -10V, I _C = -1mA, f = 1.0kHz
Noise Figure	NF	—	—	8	dB	V _{CE} = -5V, I _C = -200μA, R _S = 10Ω, f = 1.0kHz

- Notes:
- For a device mounted on minimum recommended pad layout with 1oz copper that is on a single-sided 1.6mm FR-4 PCB; the device is measured under still air conditions whilst operating in a steady state.
 - Maximum combined dissipation.
 - Short duration pulse test used to minimize self-heating effect.
 - The DC Current Gain, h_{FE}, (matched at I_C = -10mA and V_{CE} = -5V) Collector Emitter Saturation Voltage, V_{CE(sat)}, and Base Emitter Saturation Voltage, V_{BE(sat)} are matched with typical matched tolerances of 1% and maximum of 2%.

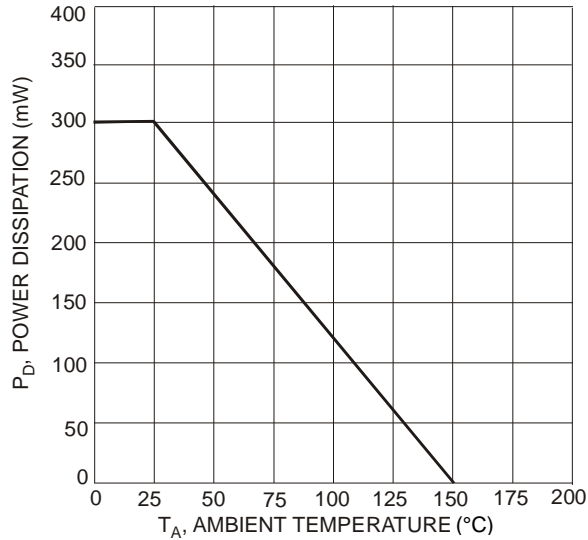


Fig. 1 Power Dissipation vs. Ambient Temperature

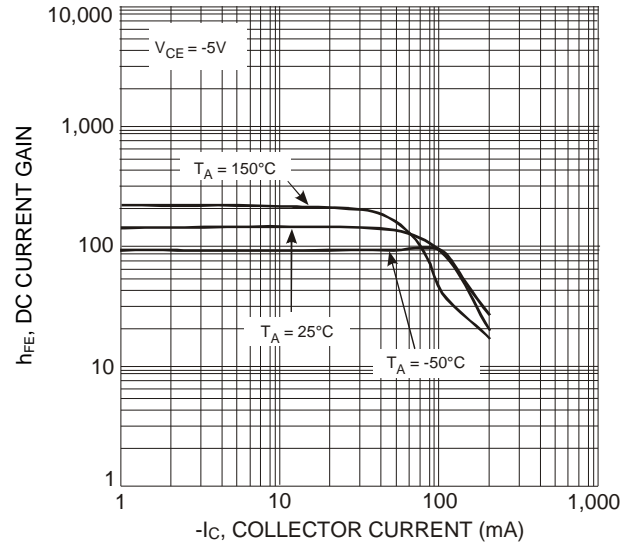


Fig. 2 Typical DC Current Gain vs. Collector Current

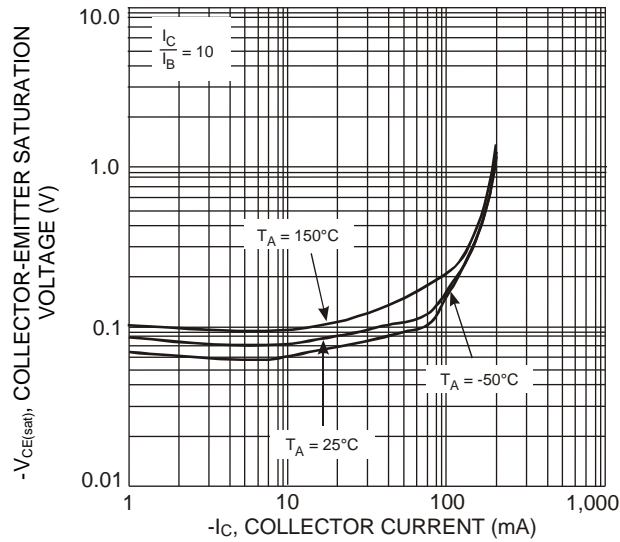


Fig. 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current

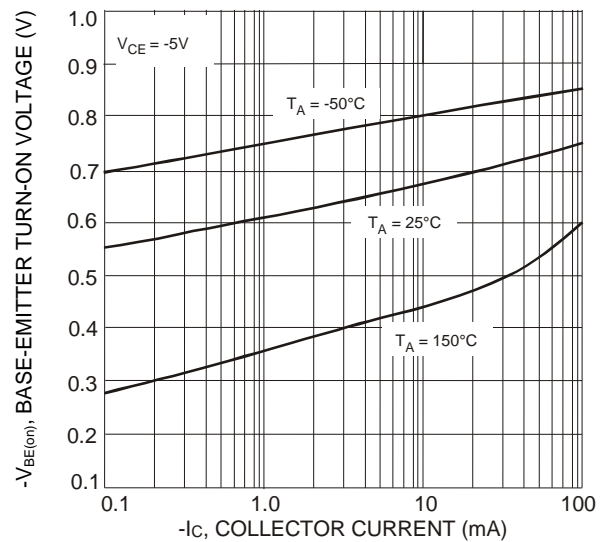


Fig. 4 Typical Base-Emitter Turn-On Voltage vs. Collector Current

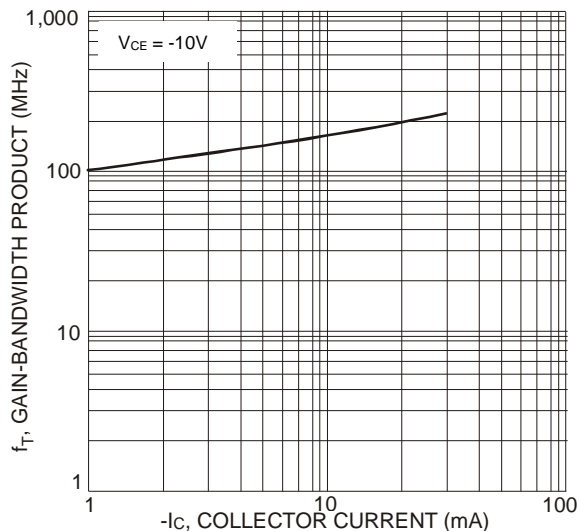
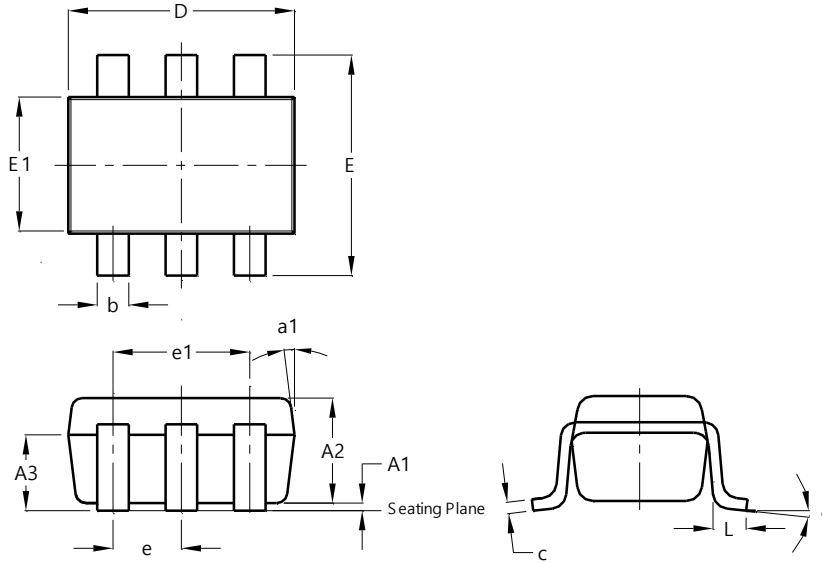


Fig. 5 Typical Gain-Bandwidth Product vs. Collector Current

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT26

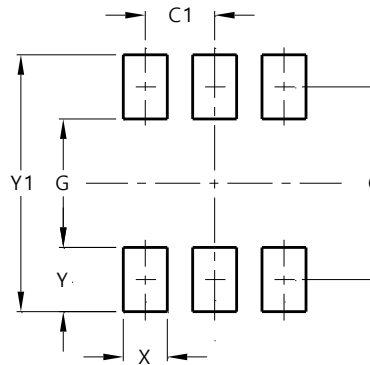


SOT26			
Dim	Min	Max	Typ
A1	0.013	0.10	0.05
A2	1.00	1.30	1.10
A3	0.70	0.80	0.75
b	0.35	0.50	0.38
c	0.10	0.20	0.15
D	2.90	3.10	3.00
e	-	-	0.95
e1	-	-	1.90
E	2.70	3.00	2.80
E1	1.50	1.70	1.60
L	0.35	0.55	0.40
a	-	-	8°
a1	-	-	7°
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT26



Dimensions	Value (in mm)
C	2.40
C1	0.95
G	1.60
X	0.55
Y	0.80
Y1	3.20

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